Hyperfast Rectifier, 3 A FRED Pt[®]



click logo to get started

www.vishay.com

DESIGN SUPPORT TOOLS



| PRIMARY CHARACTERISTICS | | | | | |
|----------------------------------|--------------------|--|--|--|--|
| I _{F(AV)} 3 A | | | | | |
| V _R | 200 V | | | | |
| V _F at I _F | 0.74 V | | | | |
| t _{rr} | 30 ns | | | | |
| T _J max. | 175 °C | | | | |
| Package | SlimSMA (DO-221AC) | | | | |
| Circuit configuration | Single | | | | |

FEATURES

- Hyperfast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- Low forward voltage drop
- Low leakage current
- Specific for output and snubber operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in snubber, boost, lighting, as high frequency rectifiers and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|---|-----------------------------------|---|-------------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Peak repetitive reverse voltage | V _{RRM} | | 200 | V | | |
| Average rectified forward current | I _{F(AV)} | $T_{\rm C} = 145 \ ^{\circ}{\rm C}^{(1)}$ | 3 | ٨ | | |
| Non-repetitive peak surge current | I _{FSM} | T _J = 25 °C | 85 | A | | |
| Operating junction and storage temperatures | T _J , T _{Stg} | | -65 to +175 | °C | | |

Note

⁽¹⁾ Device on PCB with 8 mm x 16 mm soldering lands

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | |
|--|----------------------------------|---|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | I _R = 100 μA | 200 | - | - | |
| | V _F | I _F = 3 A | - | 0.86 | 0.93 | V |
| Forward voltage | ۷F | I _F = 3 A, T _J = 125 °C | - | 0.74 | 0.78 | |
| Reverse leakage current | I _R | V _R = V _R rated | - | - | 2 | |
| neverse leakage current | | $T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$ | - | 1 | 8 | μA |
| Junction capacitance | CT | V _R = 200 V | - | 13 | - | pF |

 Revision: 07-May-2018
 1
 Document Number: 94879

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 DiodesEurope@vishay.com

 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



COMPLIANT

HALOGEN



www.vishay.com

Vishay Semiconductors

| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified) | | | | | | | |
|---|---------------------------------------|--|--|------|------|-------|----|
| PARAMETER | SYMBOL | TEST CO | MIN. | TYP. | MAX. | UNITS | |
| | Reverse recovery time t _{rr} | $I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 50$ | 0 Α/μs, V _R = 30 V | - | 26 | - | |
| Poweree receivery time | | I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A | | - | - | 30 | |
| Reverse recovery time | | T _J = 25 °C | I _F = 3 A dI _F /dt = 200 A/μs V _R = 160 V | - | 18 | - | ns |
| | | T _J = 125 °C | | - | 26 | - | |
| Deals receiver a current | ak recovery current | T _J = 25 °C | | - | 2.5 | - | ۸ |
| Peak recovery current | | T _J = 125 °C | | - | 4 | - | A |
| Reverse recovery charge Q _{rr} | T _J = 25 °C | | - | 23 | - | nC | |
| | T _J = 125 °C | | - | 50 | - | nu | |

| THERMAL - MECHANICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|---|-----------------------------------|--|------|--------|------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -65 | - | 175 | °C | |
| Thermal resistance, junction to lead | R _{thJL} | Device mounted on PCB with 8 mm x 16 mm soldering lands | - | 8 | 10 | °C/W | |
| Thermal resistance, junction to ambient | R _{thJA} | Device mounted on PCB with 2 mm x 3.5 mm soldering lands | - | 91 | 110 | C/W | |
| Approximate Weight | | | | 0.032 | | g | |
| | | | | 0.0011 | | oz. | |
| Marking device | | Case style SlimSMA (DO-221AC) | | 31 | H2 | | |

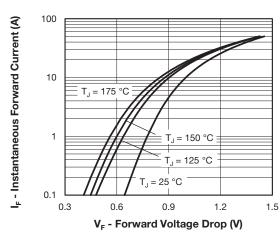
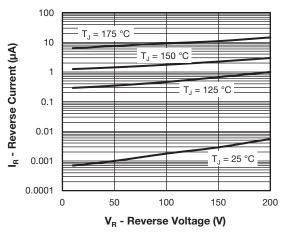
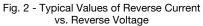
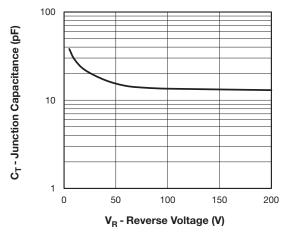


Fig. 1 - Typical Forward Voltage Drop Characteristics









www.vishay.com

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

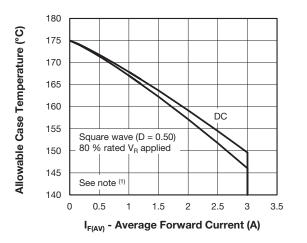


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

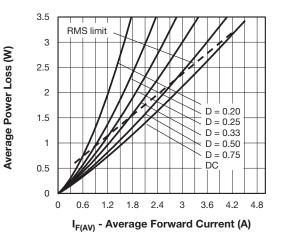
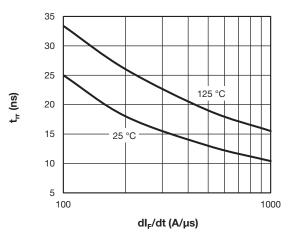
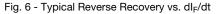


Fig. 5 - Forward Power Loss Characteristics





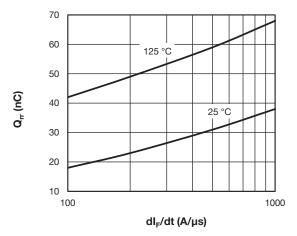


Fig. 7 - Typical Stored Charge vs. dl_F/dt

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

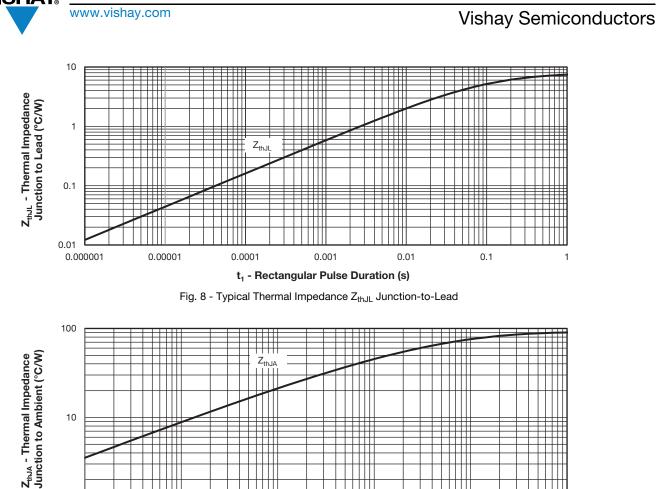
 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{Fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

Revision: 07-May-2018

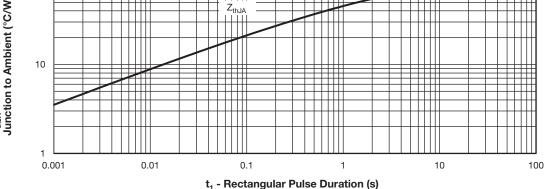
3

Document Number: 94879

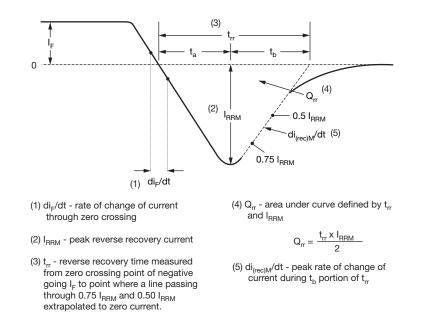
For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

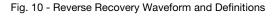


VS-3EJH02-M3









| Revision: 07-May-2018 | 4 | Document Number: 94879 |
|---|---|---------------------------------------|
| For technical questions within your region: | DiodesAmericas@vishay.com, DiodesAsia@vishay | <u>y.com, DiodesEurope@vishay.com</u> |
| | e without notice. The products describ IFIC disclaimers, set forth at <u>www.vishay.</u> | |

ORDERING INFORMATION TABLE

| Device code VS- | 3 | E | J | Н | 02 | -M3 |
|----------------------|-----------------|-----------|---|--------|----------|----------|
| | 2 | 3 | 4 | 5 | 6 | 7 |
| 1 2 3 | - Cur - Circ | rent rati | niconduo ng (3 = 3 ïguratior diode | 3 A) | oduct | |
| 4 5 | - Pro | cess typ | - | - | | |
| 6 7 | - Vol | tage coo | ast recov de (02 = gen-free | 200 V) | -complia | ant, and |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|-------------------|------------------------|-----------------------------------|--|--|--|--|
| PREFERRED P/N | QUANTITY PER REEL | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | |
| VS-3EJH02-M3/6A | 3500 | 3500 | 7"diameter plastic tape and reel | | | | |
| VS-3EJH02-M3/6B | 14 000 | 14 000 | 13"diameter plastic tape and reel | | | | |

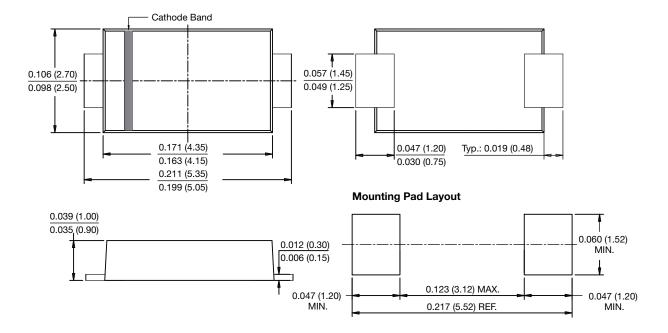
| LINKS TO RELATED DOCUMENTS | | | | |
|--|--------------------------|--|--|--|
| Dimensions <u>www.vishay.com/doc?95571</u> | | | | |
| Part marking information | www.vishay.com/doc?95562 | | | |
| Packaging information | www.vishay.com/doc?88869 | | | |





DO-221AC (SlimSMA)

DIMENSIONS in inches (millimeters)





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay: <u>VS-3EJH02-M3/6B</u> <u>VS-3EJH02-M3/6A</u>